## 20A 60V P-channel Enhancement Mode Power MOSFET

## 1 Description

These P-channel enhanced vdmosfets, used advanced trench technology and design, provide to excellent Rdson with low gate charge. Which accords with the RoHS standard.

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#### 2 Features

- Fast switching
- Low on resistance
- Low gate charge
- Low reverse transfer capacitances
- 100% single pulse avalanche energy test
- 100% ΔV<sub>DS</sub> test

# 3 Applications

- Power switching applications
- Inverter management system
- Power tools
- Automotive electronics



#### **4 Electrical Characteristics**

#### **4.1 Absolute Maximum Rating** (Tc=25°C,unless otherwise noted)

| Damanatan                            |                      | _                | Value           |                        |                        |               | Unit                   |
|--------------------------------------|----------------------|------------------|-----------------|------------------------|------------------------|---------------|------------------------|
| Parameter                            |                      | Symbol           | DH500P<br>06    | DH500P06I<br>DH500P06E | DH500P06B<br>DH500P06D | DH500P<br>06F | s                      |
| Drian-Source Voltage                 |                      | V <sub>DSS</sub> |                 | -60                    |                        |               | V                      |
| Gate-Drain Voltage                   |                      | V <sub>GSS</sub> |                 | ±                      | 20                     |               | V                      |
| Dunin Commont/continuous             | T <sub>C</sub> =25℃  |                  |                 | -2                     | 20                     |               | Α                      |
| Drain Current(continuous)            | T <sub>C</sub> =100℃ | - I <sub>D</sub> | -14             |                        |                        |               | Α                      |
| Drain Current(Pulsed) <sup>(1)</sup> |                      | I <sub>DM</sub>  | -80             |                        |                        |               | Α                      |
| Single Pulse Avalanche Energ         | y <sup>(4)</sup>     | E <sub>AS</sub>  |                 | 96                     |                        |               | mJ                     |
| Single Pulse Avalanche Curre         | nt <sup>(4)</sup>    | I <sub>AS</sub>  |                 | -19.6                  |                        |               | Α                      |
| Total Discipation                    | T <sub>a</sub> =25℃  | P <sub>tot</sub> | 2               | 2                      | 1.58                   | 2             | W                      |
| Total Dissipation                    | T <sub>C</sub> =25℃  | Ptot             | 43              | 43                     | 43                     | 18            | W                      |
| Junction Temperature                 |                      | Tj               | <b>-</b> 55∼175 |                        |                        |               | $^{\circ}\!\mathbb{C}$ |
| storage Temperature                  |                      | T <sub>stg</sub> | <b>-</b> 55∼175 |                        |                        |               | $^{\circ}\!\mathbb{C}$ |
| Maximum Temperature for sol          | dering               |                  |                 | 300                    |                        |               | $^{\circ}\!\mathbb{C}$ |

#### 4.2 Thermal Characteristics

|  |                   | Value        |                        |                        |               | Unit |
|--|-------------------|--------------|------------------------|------------------------|---------------|------|
| Parameter                                | Symbol            | DH500P<br>06 | DH500P06I<br>DH500P06E | DH500P06B<br>DH500P06D | DH500P<br>06F | S    |
| Thermal Resistance Junction to Case-sink | R <sub>thJC</sub> | 3.49         | 3.49                   | 3.49                   | 8.33          | °C/W |
| Thermal Resistance Junction to Ambient   | R <sub>thJA</sub> | 75           | 75                     | 94.88                  | 75            | °C/W |

### **4.3 Electrical Characteristics** (Tc=25°C,unless otherwise noted)

| Parameter                                 | Symbol              | Test Condition  |     | Value |      | Units  |  |
|---|---------------------|---|-----|-------|------|--------|--|
|   | Syllibol            | Test Condition  | Min | Тур   | Max  | Ullits |  |
| Off Characteristics                       | <del></del>         |   | 1   | 1     |      |        |  |
| Drain-source Breakdown<br>Voltage         | BV <sub>DSS</sub>   | $I_D$ =-250 $\mu$ A, $V_{GS}$ =0 $V$                            | -60 |       |      | V      |  |
| Drain-to-Source Leakage                   |                     | $V_{DS}$ =-60V, $V_{GS}$ =0V, $T_{C}$ =25 $^{\circ}$ C          |     |       | -1   | μA     |  |
| Current                                   | I <sub>DSS</sub>    | V <sub>DS</sub> =-48V,V <sub>GS</sub> =0V,T <sub>C</sub> =125°C |     |       | -100 | μA     |  |
| Gate-to-Source Forward<br>Leakage         | I <sub>GSSF</sub>   | V <sub>GS</sub> =+20V   |     |       | 100  | nA     |  |
| Gate-to-Source Reverse<br>Leakage         | I <sub>GSSR</sub>   | V <sub>GS</sub> =-20V   |     |       | -100 | nA     |  |
| On Characteristics                        |                     |   |     |       |      |        |  |
| Gate threshold Voltage                    | V <sub>GS(th)</sub> | $V_{DS}=V_{GS},I_{D}=-250\mu A$                                 | -1  | -1.6  | -2   | V      |  |
| Drain-source on-state                     | D                   | $V_{GS}$ =-10 $V$ , $I_D$ =-10 $A$                              |     | 58    | 70   | mΩ     |  |
| Resistance                                | R <sub>DS(on)</sub> | $V_{GS}$ =-4.5 $V$ , $I_{D}$ =-10 $A$                           |     | 70    | 84   | 11122  |  |
| Forward Transfer<br>Conductance           | <b>g</b> fs         | V <sub>DS</sub> =-5V,I <sub>D</sub> =-8A                        |     | 17    |      | S      |  |
| Dynamic Characteristics                   |                     |   |     |       |      |        |  |
| Input Capacitance                         | C <sub>iss</sub>    | \/ = 0\/  |     | 1528  |      | pF     |  |
| Output Capacitance                        | Coss                | $V_{GS}$ =0V, $V_{DS}$ =-30V,                                   |     | 90    |      |        |  |
| Reverse Transfer<br>Capacitance           | C <sub>rss</sub>    | f=1.0MHz  |     | 60    |      | ρı     |  |
| Switching Characteristics                 |                     |   | •   | '     |      |        |  |
| Turn-on Delay Time                        | t <sub>d(on)</sub>  | V <sub>DD</sub> =-30V,  |     | 6.6   |      |        |  |
| Turn-on Rise Time                         | t <sub>r</sub>      | I <sub>D</sub> =-8A,  |     | 42    |      | C      |  |
| Turn-off Delay Time                       | t <sub>d(off)</sub> | V <sub>GS</sub> =-10V,  |     | 37    |      | nS     |  |
| Turn-off Fall Time                        | t <sub>f</sub>      | $R_{GEN}=3\Omega$   |     | 63.5  |      |        |  |
| Total Gate Charge                         | Qg                  |   |     | 28.2  |      |        |  |
| Gate-to-Source Charge                     | Q <sub>gs</sub>     | I <sub>D</sub> =-8A,<br>V <sub>DD</sub> =-30V,                  |     | 7.2   |      | nC     |  |
| Gate-to-Drain("Miller")<br>Charge         | $Q_{gd}$            | V <sub>DD</sub> 30V,<br>V <sub>GS</sub> =-10V                   |     | 3.8   |      | IIC    |  |
| Drain-Source Diode Characteristics        |                     |   |     |       |      |        |  |
| Diode Forward Voltage <sup>(3)</sup>      | V <sub>FSD</sub>    | V <sub>GS</sub> =0V,I <sub>S</sub> =-8A                         |     |       | -1.2 | V      |  |
| Diode Forward Current                     | Is                  |   |     |       | -20  | Α      |  |
| Reverse Recovery Time(3)                  | t <sub>rr</sub>     | Tյ=25°C,I <sub>F</sub> =-8A,                                    |     | 29    |      | nS     |  |
| Reverse Recovery<br>Charge <sup>(3)</sup> | Q <sub>rr</sub>     | dl <sub>F</sub> /dt=100A/μS,V <sub>GS</sub> =0V                 |     | 12.8  |      | nC     |  |

#### Notes:

- 1: Repetitive rating, pulse width limited by maximum junction temperature.
- 2: Surface mounted on FR4 Board, t≤10sec.
- 3: Pulse width  $\leq$  300 $\mu$ s, duty cycle  $\leq$  2%.
- 4. L=0.5mH,I<sub>D</sub>=-19.6A,V<sub>DD</sub>=-50V,V<sub>GATE</sub>=-60V,Start T<sub>J</sub>=25 $^{\circ}$ C.

## 5 Typical characteristics diagrams

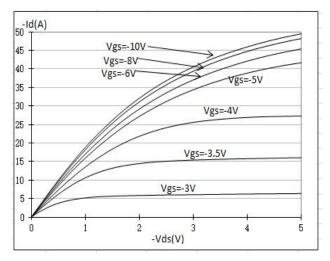


Figure 1 Output Characteristics

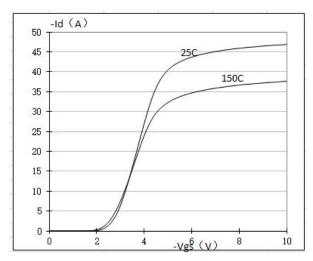


Figure 2 Transfer Characteristics

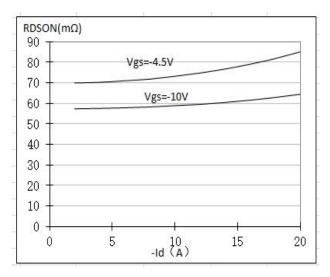


Figure 3. On-resistance vs. Drain Current

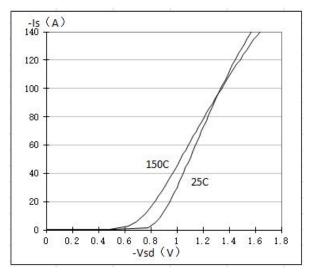


Figure 4. Source- Drain Diode Forward

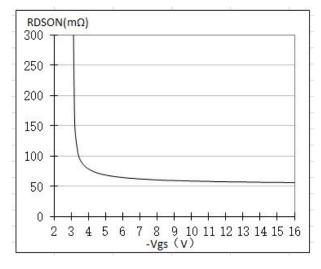


Figure 5. On-resistance vs.Vgs

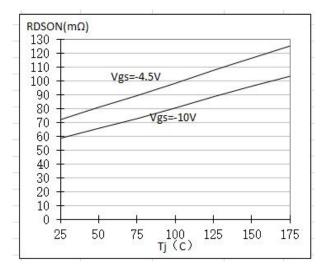


Figure 6. on Resistance vs. Junction Temperature



# 5 Typical characteristics diagrams(continues)

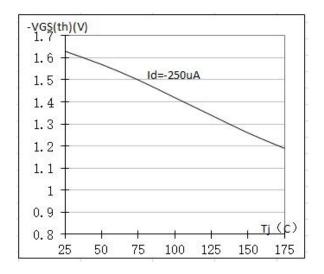


Figure 7. VTH vs. Junction Temperature

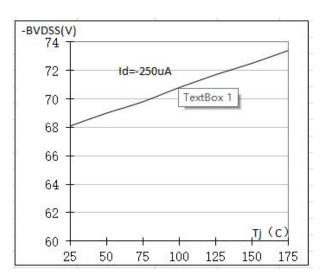


Figure 8. BVdss vs. Junction Temperature

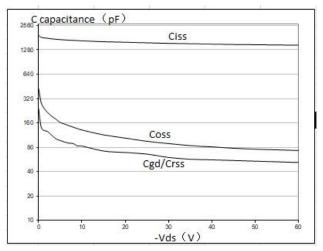


Figure 9. Capacitance vs Vds

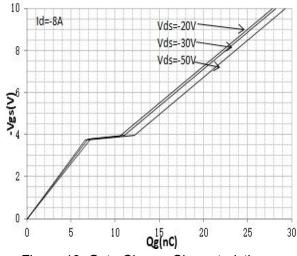


Figure 10. Gate Charge Characteristics

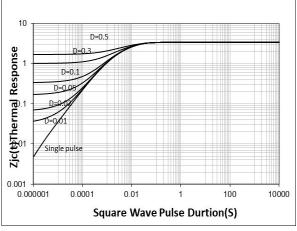


Figure 11. Normalized Maximum Transient
Thermal Impedance

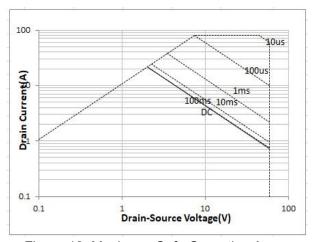
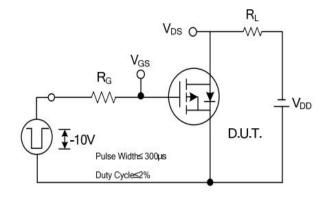


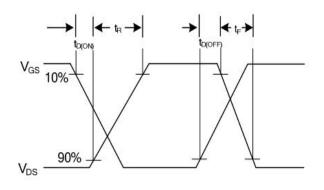
Figure 12. Maximum Safe Operating Area



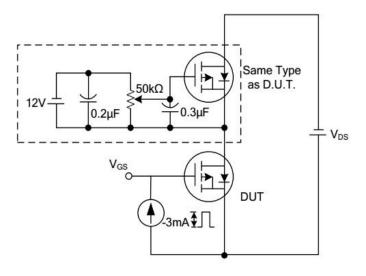
# 6 Typical Test Circuit and Waveform



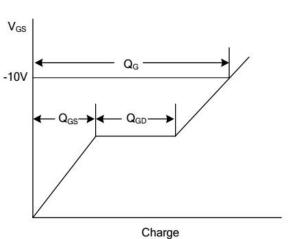
**Switching Test Circuit** 



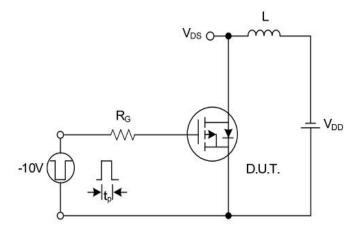
**Switching Waveforms** 



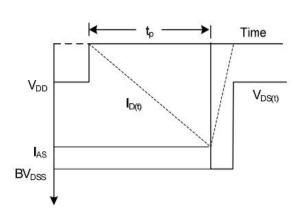
**Gate Charge Test Circuit** 



**Gate Charge Waveform** 

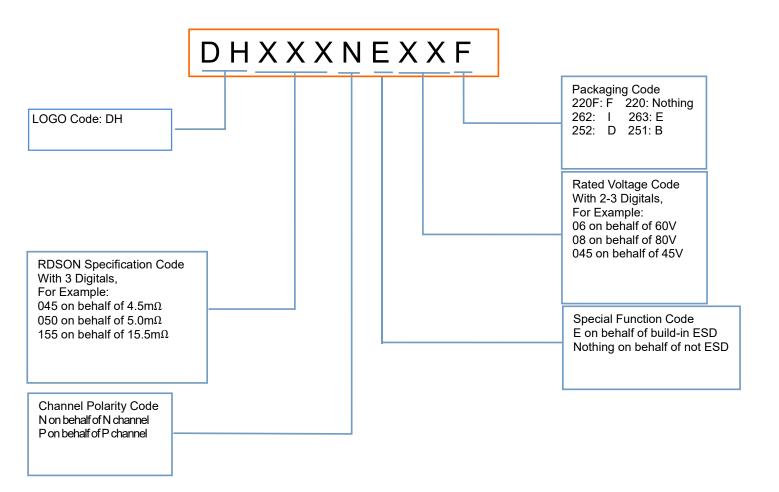


**Unclamped Inductive Switching Test Circuit** 



**Unclamped Inductive Switching Waveforms** 

## 7 Product Names Rules

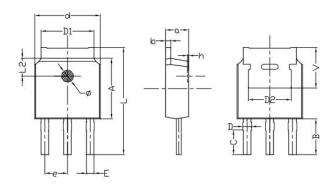


## 8 Product Specifications and Packaging Models

| Product Model | Package Type | Mark Name | RoHS    | Package     | Quantity |
|---------------|--------------|-----------|---------|-------------|----------|
| DH500P06      | TO-220C      | DH500P06  | Pb-free | Tube        | 1000/box |
| DH500P06F     | TO-220F      | DH500P06F | Pb-free | Tube        | 1000/box |
| DH500P06B     | TO-251       | DH500P06B | Pb-free | Tube        | 3000/box |
| DH500P06D     | TO-252       | DH500P06D | Pb-free | Tape & Reel | 2500/box |
| DH500P06I     | TO-262       | DH500P06I | Pb-free | Tube        | 1000/box |
| DH500P06E     | TO-263       | DH500P06E | Pb-free | Tape & Reel | 800/box  |

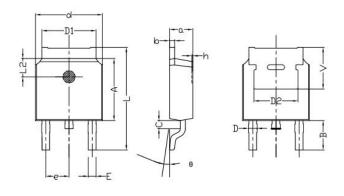
### 9 Dimensions

### TO-251B PACKAGE OUTLINE DIMENSIONS



| CL 1   | Dimensions I | n Millimeters | Dimensions | In Inches |
|--------|--------------|---------------|------------|-----------|
| Symbol | min.         | max.          | min.       | max.      |
| a      | 2. 20        | 2. 40         | 0. 087     | 0. 0946   |
| b      | 0.46         | 0. 58         | 0.018      | 0.023     |
| С      | 2.45         | 2. 65         | 0.097      | 0.104     |
| D      | 0.80         | 0. 90         | 0.032      | 0.035     |
| d      | 6.30         | 6.70          | 0. 248     | 0. 264    |
| D1     | 5. 00        | 5. 50         | 0. 197     | 0. 217    |
| D2     | TYF          | 4.83          | TYP 0.190  |           |
| A      | 5. 80        | 6. 20         | 0. 228     | 0. 244    |
| e      | 2. 19        | 2.39          | 0.086      | 0.094     |
| L      | 10. 40       | 11.00         | 0. 4098    | 0. 4334   |
| В      | 3.50         | 3. 70         | 0. 1379    | 0. 1458   |
| L2     | 1. 5         | 1.8           | 0.059      | 0.071     |
| Ф      | 1.10         | 1. 30         | 0. 0433    | 0.0512    |
| h      | 0.00         | 0. 30         | 0.000      | 0.012     |
| V      | 5. 25        | 5. 85         | 0. 207     | 0. 230    |
| Е      | 0.60         | 0.80          | 0. 0236    | 0. 0315   |

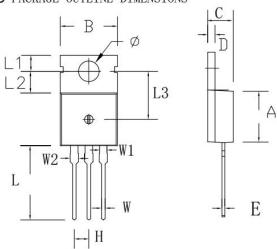
### TO-252B PACKAGE OUTLINE DIMENSIONS



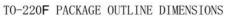
| CL-1   | Dimensions In | Millimeters | Dimensions | In Inches |  |
|--------|---------------|-------------|------------|-----------|--|
| Symbol | min.          | max.        | min.       | max.      |  |
| a      | 2.20          | 2. 40       | 0.087      | 0.095     |  |
| b      | 0.46          | 0. 58       | 0.018      | 0.023     |  |
| c      | 0.70          | 0.90        | 0.028      | 0.035     |  |
| D      | 0.80          | 1.00        | 0.032      | 0.039     |  |
| d      | 6.30          | 6. 70       | 0. 248     | 0. 264    |  |
| D1     | 5.00          | 5. 50       | 0. 197     | 0.217     |  |
| D2     | TYP           | 4.83        | TYP 0.190  |           |  |
| A      | 5. 80         | 6. 20       | 0. 228     | 0. 244    |  |
| е      | 2.19          | 2. 39       | 0.086      | 0.094     |  |
| L      | 9. 40         | 10. 40      | 0.370      | 0.409     |  |
| В      | 2.6           | 3. 2        | 0. 102     | 0. 126    |  |
| L2     | 1.5           | 1.8         | 0.059      | 0.071     |  |
| θ      | 0             | 8           | 0          | 8         |  |
| h      | 0             | 0.3         | 0          | 0.012     |  |
| V      | 5. 25         | 5. 85       | 0. 207     | 0. 230    |  |
| Е      | 0.6           | 0.8         | 0.024      | 0.032     |  |

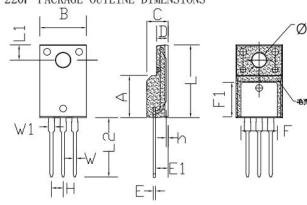
# 9 Dimensions(continues)

TO-220C PACKAGE OUTLINE DIMENSIONS



| C-1-1  | Dimensions I | n Millimeters | Dimensions | In Inches |
|--------|--------------|---------------|------------|-----------|
| Symbol | min.         | max.          | min.       | max.      |
| A      | 8.80         | 9. 30         | 0.346      | 0.366     |
| В      | 9. 70        | 10.30         | 0.382      | 0.406     |
| С      | 4. 25        | 4. 75         | 0. 167     | 0.187     |
| D      | 1. 20        | 1.45          | 0.047      | 0.057     |
| Е      | 0.40         | 0.60          | 0.016      | 0.024     |
| Н      | 2. 5         | 4 TYP         | 0.100      | TYP       |
| W      | 0.60         | 0.95          | 0.024      | 0.037     |
| W1     | 1.05         | 1. 45         | 0.041      | 0.057     |
| W2     | 1. 20        | 1.60          | 0.047      | 0.063     |
| L      | 12.60        | 13. 40        | 0.496      | 0.528     |
| L1     | 2. 45        | 2. 95         | 0.096      | 0.116     |
| L2     | 3. 45        | 3. 95         | 0. 136     | 0. 156    |
| L3     | 8. 15        | 8.65          | 0. 321     | 0.341     |
| Φ      | 3. 50        | 3. 90         | 0. 138     | 0. 154    |
|        | -            |               |            |           |

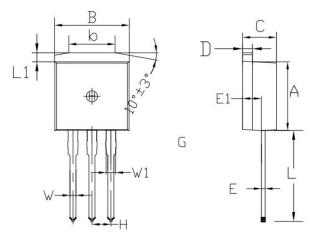




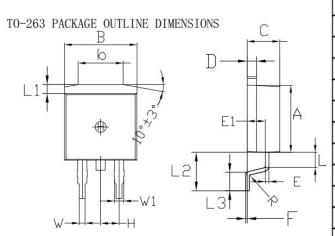
| Cl 1   | Dimensions I | n Millimeters | Dimensions | In Inches |
|--------|--------------|---------------|------------|-----------|
| Symbol | min.         | max.          | min.       | max.      |
| A      | 8. 80        | 9. 30         | 0.346      | 0.366     |
| В      | 10.00        | 10.50         | 0.394      | 0.413     |
| С      | 4. 30        | 4. 90         | 0. 169     | 0. 193    |
| D      | 2. 30        | 2. 70         | 0.091      | 0. 106    |
| L      | 15, 55       | 16. 15        | 0.612      | 0.636     |
| h      | 0.40         | 0.60          | 0.016      | 0.024     |
| L1     | 3. 15        | 3. 55         | 0. 124     | 0.140     |
| L2     | 12.65        | 13. 35        | 0.498      | 0. 526    |
| W      | 0.70         | 0. 90         | 0.028      | 0.035     |
| W1     | 1.15         | 1.55          | 0.045      | 0.061     |
| Н      | 2.54         | 4 TYP         | 0.100 TYP  |           |
| Е      | 0.48         | 0. 53         | 0.019      | 0.021     |
| Φ      | 2.90         | 3. 40         | 0.114      | 0.134     |
| E1     | 2. 40        | 2. 90         | 0.094      | 0.114     |
| F      | 7. 75        | 8, 25         | 0. 305     | 0. 325    |
| F1     | 7. 35        | 7.85          | 0. 289     | 0.309     |

# 9 Dimensions(continues)

TO-262 PACKAGE OUTLINE DIMENSIONS



| CL . 1 | Dimensions In | Millimeters | Dimensions | In Inches |
|--------|---------------|-------------|------------|-----------|
| Symbol | min.          | max.        | min.       | max.      |
| A      | 8. 80         | 9. 30       | 0.346      | 0.366     |
| В      | 9. 70         | 10.30       | 0.382      | 0.406     |
| С      | 4. 25         | 4. 75       | 0. 167     | 0. 187    |
| D      | 1. 20         | 1. 45       | 0.047      | 0.057     |
| Е      | 0.40          | 0.60        | 0.016      | 0.024     |
| L      | 12, 25        | 13. 75      | 0. 482     | 0. 541    |
| L1     | 1. 15         | 1. 45       | 0.045      | 0.057     |
| E1     | 2. 4          | 2.6         | 0.0945     | 0. 1024   |
| W      | 0.80          | 0.82        | 0.0315     | 0.034     |
| W1     | 1. 20         | 1.30        | 0.047      | 0.051     |
| Н      | 2. 5          | 4 TYP       | 0. 200     | TYP       |
| b      | 5. 50         | 6. 50       | 0.216      | 0.256     |



| Symbol   | Dimensions In | Millimeters | Dimensions | In Inches |
|----------|---------------|-------------|------------|-----------|
| Syllido1 | min.          | max.        | min.       | max.      |
| A        | 8.80          | 9.30        | 0.346      | 0.366     |
| В        | 9.70          | 10.30       | 0.382      | 0.406     |
| С        | 4. 25         | 4. 75       | 0. 167     | 0.187     |
| D        | 1.20          | 1.45        | 0.047      | 0.057     |
| Е        | 0. 40         | 0. 60       | 0.016      | 0.024     |
| L        | 1.90          | 2. 30       | 0.075      | 0.091     |
| L1       | 1.15          | 1.45        | 0.045      | 0.057     |
| R        | 0.24          | 0. 26       | 0.0095     | 0.0102    |
| W        | 0.80          | 0.82        | 0. 0315    | 0.0323    |
| W1       | 1.20          | 1. 30       | 0.047      | 0.051     |
| Н        | 2. 5          | 4 TYP       | 0.200 TYP  |           |
| b        | 5. 50         | 6. 50       | 0. 216     | 0.256     |
| E1       | 2. 4          | 2. 6        | 0.0946     | 0.1024    |
| L2       | 5. 20         | 5. 80       | 0. 205     | 0. 228    |
| L3       | 2. 20         | 3. 20       | 0.087      | 0.126     |
| F        | 0.03          | 0. 23       | 0.0012     | 0.0091    |



#### 10 Attentions

- Jiangsu Donghai Semiconductor Technology CO.,LTD. reserves the right to change the specification without prior notice! The customer should obtain the latest version of the information before making the order and verify that the information is complete and up to date.
- It is the responsibility of the purchaser for any failure or failure of any semiconductor product under certain conditions. It is the responsibility of the purchaser to comply with safety standards and to take safety measures in the system design and machine manufacturing of Donghai products in order to avoid potential risk of failure. Injury or property damage.
- Product promotion is endless, our company will be dedicated to provide customers with better products.

# 11 Appendix

Revision history:

| Date       | REV. | Description | Page |
|------------|------|-------------|------|
| 2021.09.25 | 1.0  | Original    |      |